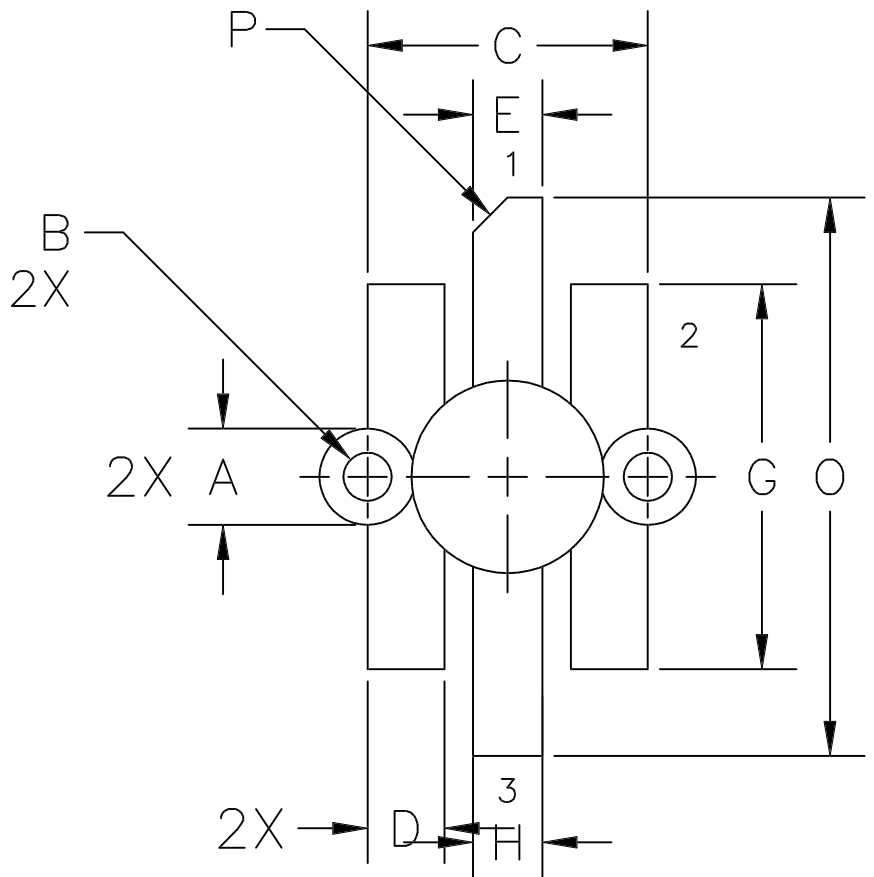
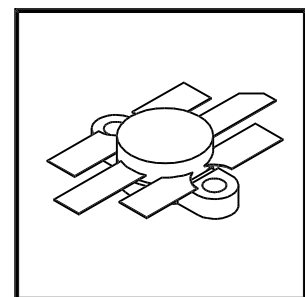
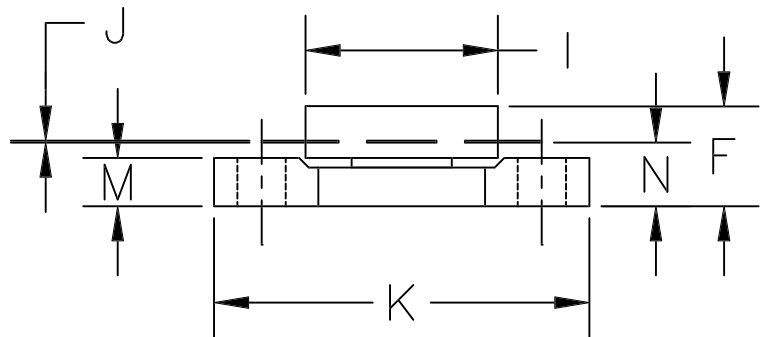


STYLE 1:
PIN1 = COLLECTOR
2 = BASE (4X)
3 = EMITTER

STYLE 2:
PIN1 = COLLECTOR
2 = EMITTER (4X)
3 = BASE



DIM	MILLIMETER	TOL	INCHES	TOL
A	6.35 DIA	.13	.250 DIA	.005
B	3.17 DIA	.13	.125 DIA	.005
C	18.49	.13	.728	.005
D	5.08	.13	.200	.005
E	4.57	.13	.180	.005
F	6.60	REF	.260	REF
G	25.40	.25	1.000	.010
H	6.69	.13	.224	.005
I	12.70 DIA	.13	.500 DIA	.005
J	0.13	.02	.005	.001
K	24.76	.13	.975	.005
M	3.17	.13	.125	.010
N	4.19	.13	.165	.005
O	36.83	.25	1.450	.010
P	45°	5°	45°	5°



GHz TECHNOLOGY
 RF - MICROWAVE SILICON POWER TRANSISTORS

DWG NO.

55HW